







SN54HCT574, SN74HCT574

SCLS177G - MARCH 1984 - REVISED JULY 2022

SNx4HCT574 Octal Edge-Triggered D-Type Flip-Flips With 3-State Outputs

1 Features

- Operating voltage range of 4.5 V to 5.5 V
- High-current 3-state noninverting outputs drive bus lines directly or up to 15 LSTTL loads
- Low power consumption, 80-µA max I_{CC}
- Typical t_{pd} = 22 ns
- ±6-mA output drive at 5 V
- Low input current of 1 µA max
- Inputs are TTL-voltage compatible
- **Bus-structured pinout**

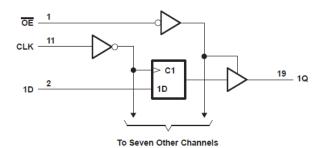
2 Description

These octal edge-triggered D-type flip-flops feature 3-state outputs designed specifically for bus driving. The 'HCT574 devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
SN74HCT574DW	SOIC (20)	12.80 mm × 7.50 mm
SN74HCT574DBR	SSOP (20)	7.20 mm × 5.30 mm
SN74HCT574N	PDIP (20)	25.40 mm × 6.35 mm
SN74HCT574NSR	SO (20)	15.00 mm × 5.30 mm
SN74HCT574PW	TSSOP (20)	6.50 mm × 4.40 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Logic Diagram (Positive Logic)

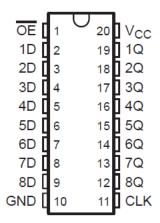


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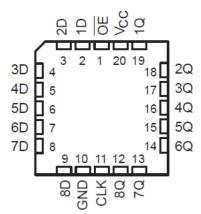
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3 Revision History NOTE: Page numbers for previous revisions m	ay differ fr	om page numbers in the current version.	
Changes from Revision F (January 2022) to	Revision	G (July 2022)	Page
		sed. DW was 58 is now 109.1, DB was 70 is no vas 83 is now 131.8	
Changes from Revision E (August 2003) to	Revision	F (January 2022)	Page



4 Pin Configuration and Functions



DB, DW, N, NS, or PW package 20-Pin SSOP, SOIC, PDIP, SO, TSSOP Top View



FK Package 20-Pin LCCC Top View



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
I _{IK}	Input clamp current ⁽²⁾	$V_{l} < 0 \text{ or } V_{l} > V_{CC}$		±20	mA
I _{OK}	Output clamp current ⁽²⁾	$V_O < 0$ or $V_O > V_{CC}$		±20	mA
Io	Continuous output current	V _O = 0 to V _{CC}		±35	mA
	Continuous current through V _{CC} or GNI)		±70	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature range		-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended" operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions(1)

			SN	54HCT574		SN	74HCT574		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNII
V _{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V _{IH}	High-level input voltage	V _{CC} = 4.5 V to 5.5 V	2			2			V
V _{IL}	Low-level input voltage	V _{CC} = 4.5 V to 5.5 V			0.8			0.8	V
VI	Input voltage		0		V _{CC}	0		V _{CC}	V
Vo	Output voltage		0		V_{CC}	0		V_{CC}	V
Δt/Δν	Input transition rise/fall time				500			500	ns
T _A	Operating free-air temperatu	re	-55		125	-40		85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

5.3 Thermal Information

		DW (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL	. METRIC	20 PINS	20 PINS	20 PINS	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	109.1	122.7	84.6	113.4	131.8	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	76	81.6	72.5	78.6	72.2	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	77.6	77.5	65.3	78.4	82.8	°C/W
Ψлт	Junction-to-top characterization parameter	51.5	46.1	55.3	47.1	21.5	°C/W
ΨЈВ	Junction-to-board characterization parameter	77.1	77.1	65.2	78.1	82.4	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.



5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	NDITIONS	V	T,	_A = 25°C	,	SN54HC	T574	SN74HC	CT574	UNIT
PARAMETER	IESI CO	SNOTTION	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
V _{OH}		I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH		I _{OH} = −6 mA	4.5 V	3.98	4.3		3.7		3.84		V
V _{OL}	V _I = V _{IH} or V _{IL}	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
VOL	VI - VIH OI VIL	I _{OL} = 6 mA	4.5 V		0.17	0.26		0.4		0.33	V
l _l	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
I _{OZ}	$V_O = V_{CC}$ or 0		5.5 V		±0.01	±0.5		±10		±5	μΑ
I _{CC}	$V_I = V_{CC}$ or 0,	I _O = 0	5.5 V			8		160		80	μΑ
ΔI _{CC} (1)	One input at 0.5 Other inputs at		5.5 V		1.4	2.4		3		2.9	mA
C _i			4.5 V to 5.5 V		3	10		10		10	pF

⁽¹⁾ This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or V_C.

5.5 Timing Requirements

over recommended operating free-air temperature range (unless otherwise noted)

	1 5 1	_	, ,		,				
		V	T _A = 25	°C	SN54HC	T574	SN74HC	Γ574	UNIT
		V _{CC}	MIN	MAX	MIN	MAX	MIN	MAX	UNII
f	Clask fraguency			30		20		24	MHz
f _{clock}	Clock frequency	5.5 V		33		22		27	IVII IZ
+	Pulse duration, CLK high or low	4.5 V	16		24		20		ns
t _w	Pulse duration, CER high or low	5.5 V	14		22		18		115
+	Setup time data before CLKA	4.5 V	20		30		25		ns
^L SU	Setup time, data before CEN	5.5 V	17		27		23		115
•	Hold time data after CLKA	4.5 V	5		5		5		no
чh	Hold time, data after CLK↑		5		5		5		ns
t _{su}	Setup time, data before CLK↑ Hold time, data after CLK↑	5.5 V	17 5		27 5		23 5		

5.6 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	V	T,	= 25°C		SN54HC	T574	SN74HC	T574	UNIT	
PARAMETER	(INPUT)	(OUTPUT)	V _{CC}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT	
f		4.5 V	30	36		20		24		MHz		
Imax	f _{max}		5.5 V	33	40		22		27		IVITIZ	
	CLK	Any O	4.5 V		30	36		54		45	no	
t_{pd}	CLK	LK Any Q	5.5 V		25	32		48		41	ns	
+	ŌĒ	Any Q	4.5 V		26	30		45		38	ns	
t _{en}	OL	Ally Q	5.5 V		23	27		41		34	115	
4	ŌĒ	Δην. Ο	4.5 V		23	30		45		38	no	
$t_{\sf dis}$	OE	Any Q	Any Q	5.5 V		22	27		41		34	ns
+.		Any Q	4.5 V		10	12		18		15	ns	
t _t		Ally Q	5.5 V		9	11		16		14	115	



5.7 Switching Characteristics

over recommended operating free-air temperature range, C_L = 150 pF (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	V _{cc}	TA	T _A = 25°C			T574	SN74HCT574		UNIT
PARAMETER	(INPUT)	(OUTPUT)	▼CC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
f			4.5 V	30	36		20		24		MHz
f _{max}			5.5 V	33	40		22		27		IVII IZ
4 .	CLK	Any Q	4.5 V		40	53		80	·	66	nc
t _{pd}	CLK	Ally Q	5.5 V		35	47		71		60	ns
+	ŌĒ	Any Q	4.5 V		34	47		71		59	ns
^L en	OL	Ally Q	5.5 V		29	39		94		78	115
+		Any O	4.5 V		18	42		63		53	no
t _t		Any Q	5.5 V		16	38		57		48	ns

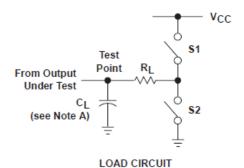
5.8 Operating Characteristics

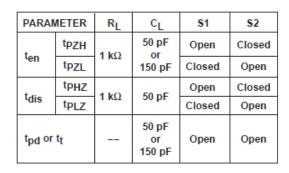
T_A = 25°C

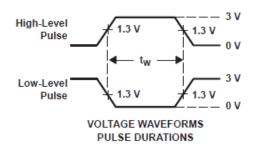
	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per flip-flop	No load	93	pF

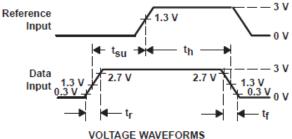


6 Parameter Measurement Information

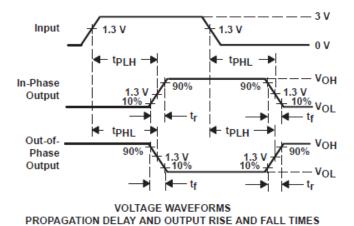


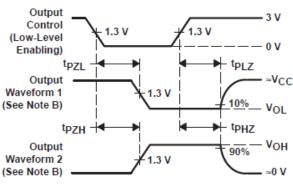






VOLTAGE WAVEFORMS
SETUP AND HOLD AND INPUT RISE AND FALL TIMES





VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES FOR 3-STATE OUTPUTS

- A. C_L includes probe and test-fixture capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_r = 6 ns, t_f = 6 ns.
- D. For clock inputs, fmaxis measured when the input duty cycle is 50%.
- E. The outputs are measured one at a time with one input transition per measurement.
- F. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- G. t_{PZL} and t_{PZH} are the same as t_{en} .
- H. t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 6-1. Load Circuit and Voltage Waveforms



7 Detailed Description

7.1 Overview

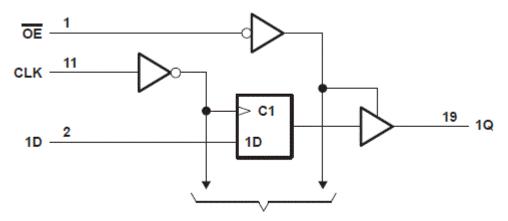
These octal edge-triggered D-type flip-flops feature 3-state outputs designed specifically for bus driving. The 'HCT574 devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

The eight flip-flops enter data on the low-to-high transition of the clock (CLK) input.

A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without interface or pullup components.

 $\overline{\text{OE}}$ does not affect the internal operations of the flip-flops. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

7.2 Functional Block Diagram



To Seven Other Channels

7.3 Device Functional Modes

Table 7-1. Function Table (Each Flip-Flop)

	INPUTS		OUTPUT
ŌĒ	CLK	D	Q
L	1	Н	Н
L	1	L	L
L	H or L	Х	Q_0
Н	X	Х	Z



8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC} , whichever makes more sense for the logic function or is more convenient.



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

10.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74HCT574DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574	Samples
SN74HCT574DW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574	Samples
SN74HCT574DWG4	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574	Samples
SN74HCT574DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574	Samples
SN74HCT574DWRG4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574	Samples
SN74HCT574N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT574N	Samples
SN74HCT574NE4	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 85	SN74HCT574N	Samples
SN74HCT574NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT574	Samples
SN74HCT574PW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574	Samples
SN74HCT574PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574	Samples
SN74HCT574PWT	ACTIVE	TSSOP	PW	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT574	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



PACKAGE OPTION ADDENDUM

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- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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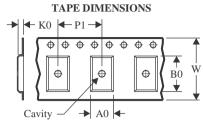
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.



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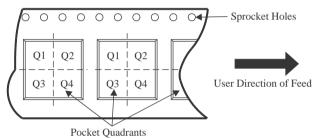
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

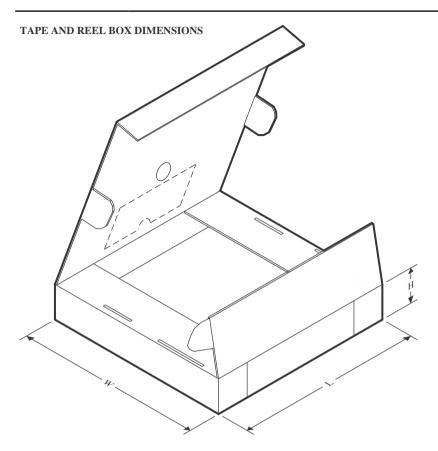


*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT574DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74HCT574DWR	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
SN74HCT574NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT574NSR	so	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74HCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74HCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74HCT574PWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



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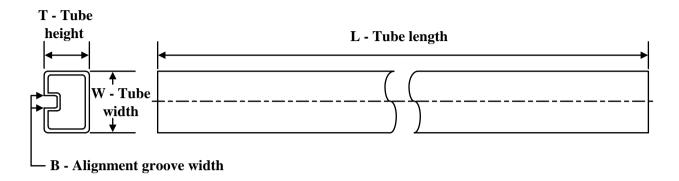
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT574DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74HCT574DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74HCT574NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74HCT574NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74HCT574PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74HCT574PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74HCT574PWT	TSSOP	PW	20	250	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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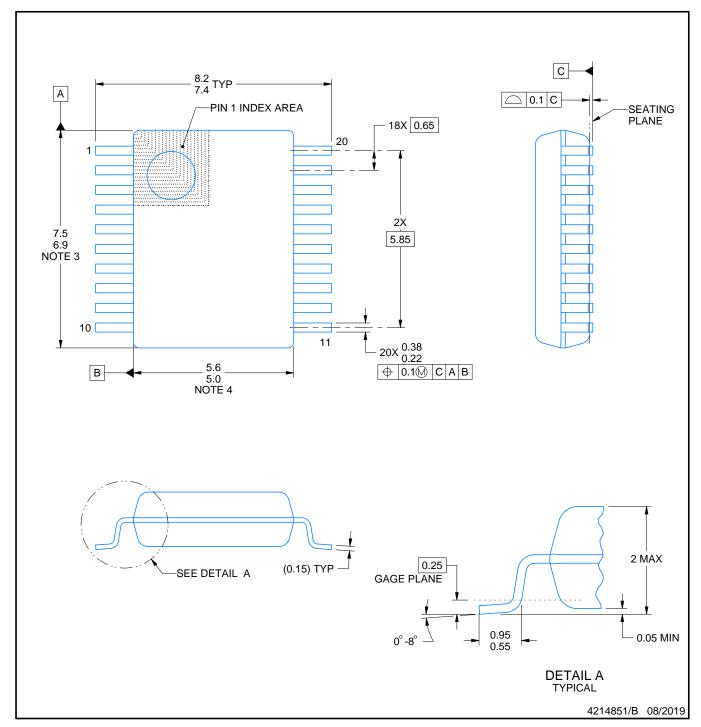
TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
SN74HCT574DW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74HCT574DWG4	DW	SOIC	20	25	507	12.83	5080	6.6
SN74HCT574N	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT574NE4	N	PDIP	20	20	506	13.97	11230	4.32
SN74HCT574PW	PW	TSSOP	20	70	530	10.2	3600	3.5



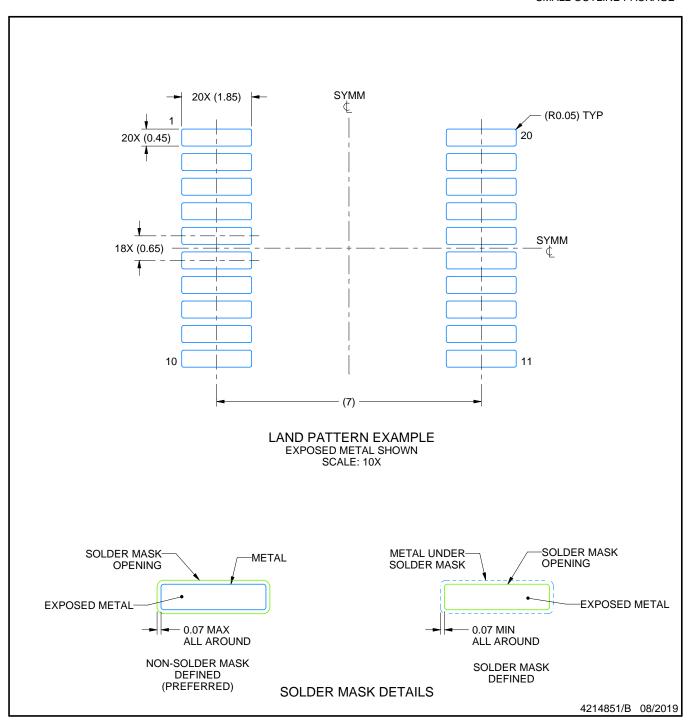


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



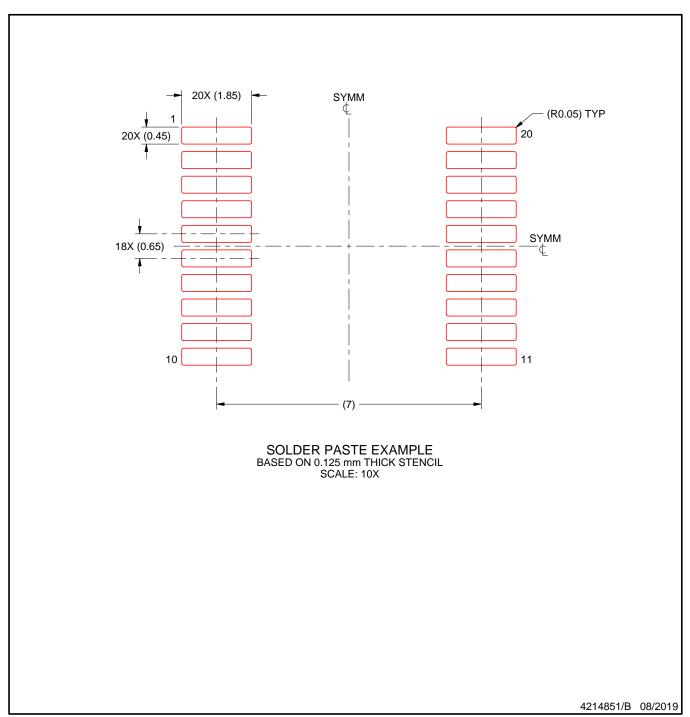


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC

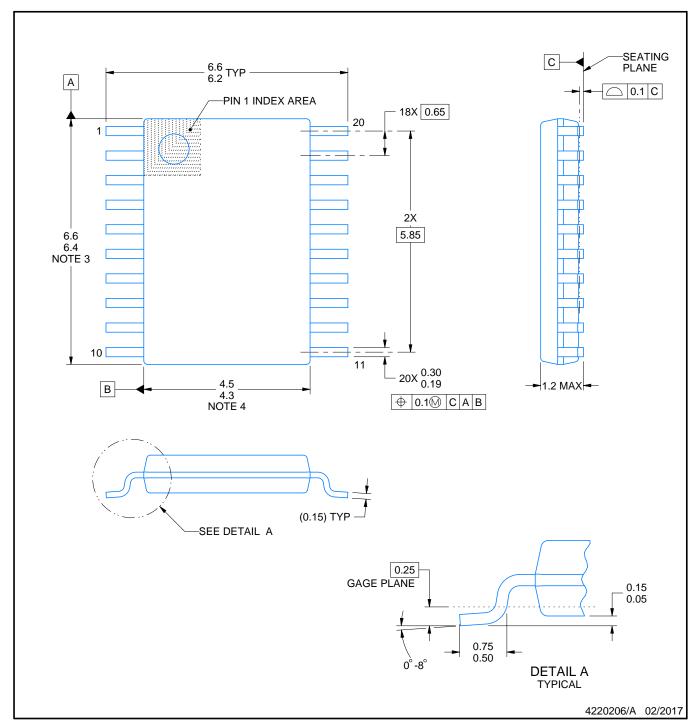


NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.





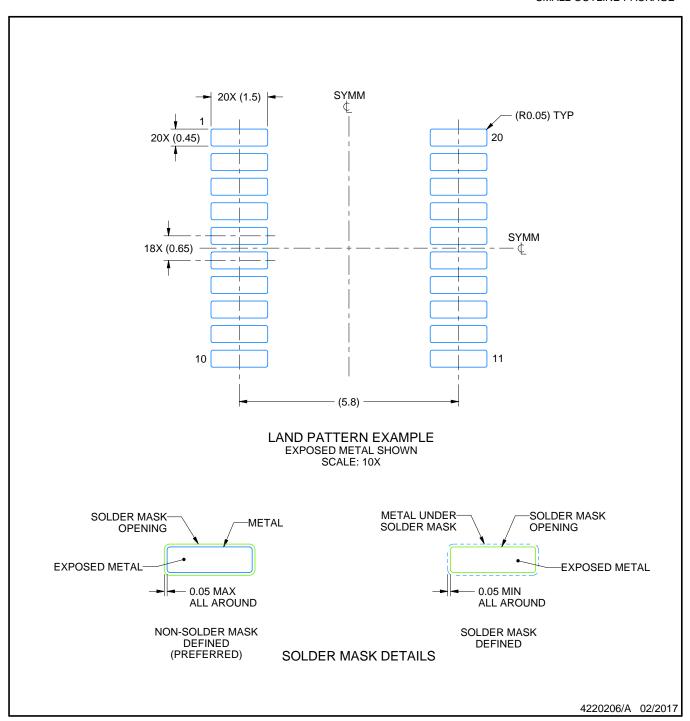


- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



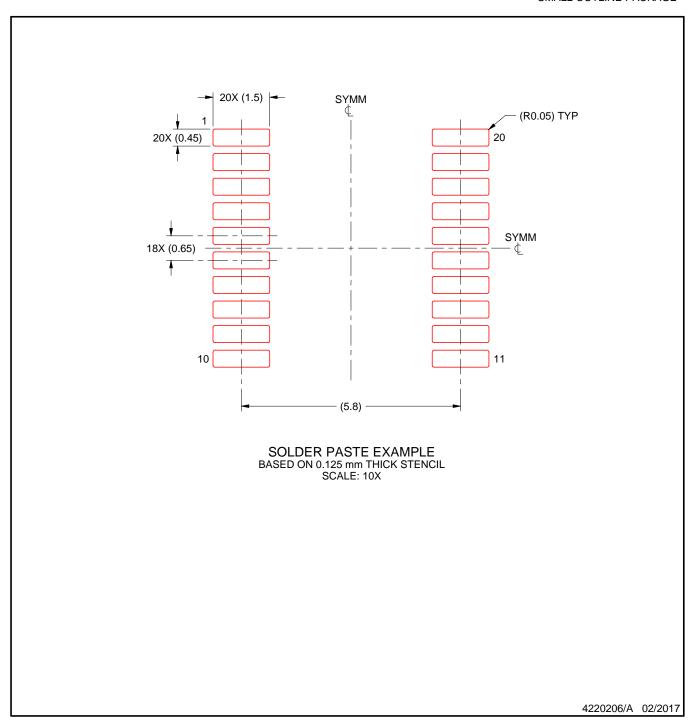


NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





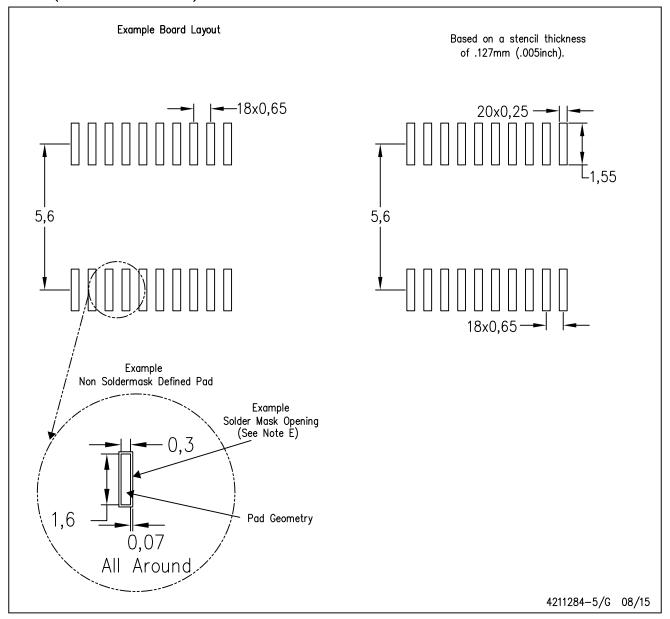
NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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